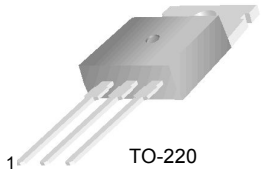
FAIRCHILD SEMICONDUCTOR®

October 2008

TIP100/TIP101/TIP102

NPN Epitaxial Silicon Darlington Transistor

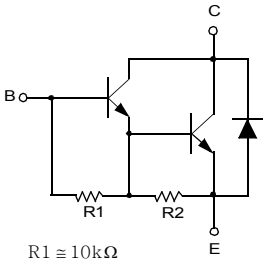
- Monolithic Construction With Built In Base-Emitter Shunt Resistors
- High DC Current Gain : h_{FE}=1000 @ V_{CE}=4V, I_C=3A (Min.)
- Collector-Emitter Sustaining Voltage
- Low Collector-Emitter Saturation Voltage
- Industrial Use
- Complementary to TIP105/106/107



TO-220

1.Base 2.Collector 3.Emitter

Equivalent Circuit



$R1 \cong 10k\Omega$
$R2 \cong 0.6k\Omega$

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage : TIP100	60	V
	: TIP101	80	V
	: TIP102	100	V
V_{CEO}	Collector-Emitter Voltage : TIP100	60	V
	: TIP101	80	V
	: TIP102	100	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	8	A
I_{CP}	Collector Current (Pulse)	15	A
I_B	Base Current (DC)	1	A
P_C	Collector Dissipation (T_a=25°C)	2	W
	Collector Dissipation (T_C=25°C)	80	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 65 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage					
	: TIP100	I_C = 30mA, I_B = 0	60			V
	: TIP101		80			V
	: TIP102		100			V
I_{CEO}	Collector Cut-off Current					
	: TIP100	V_{CE} = 30V, I_B = 0			50	μA
	: TIP101	V_{CE} = 40V, I_B = 0			50	μA
	: TIP102	V_{CE} = 50V, I_B = 0			50	μA
I_{CBO}	Collector Cut-off Current					
	: TIP100	V_{CE} = 60V, I_E = 0			50	μA
	: TIP101	V_{CE} = 80V, I_E = 0			50	μA
	: TIP102	V_{CE} = 100V, I_E = 0			50	μA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0			2	mA
h_{FE}	DC Current Gain	V_{CE} = 4V, I_C = 3A	1000		20000	
		V_{CE} = 4V, I_C = 8A	200			
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 3A, I_B = 6mA			2	V
		I_C = 8A, I_B = 80mA			2.5	V
V_{BE}(on)	Base-Emitter On Voltage	V_{CE} = 4V, I_C = 8A			2.8	V
C_{ob}	Output Capacitance	V_{CB} = 10V, I_E = 0, f = 0.1MHz			200	pF

* Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

Typical Characteristics

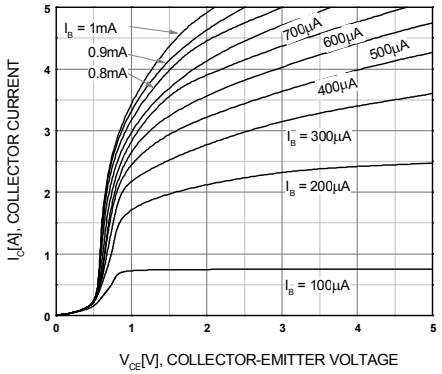


Figure 1. Static Characteristic

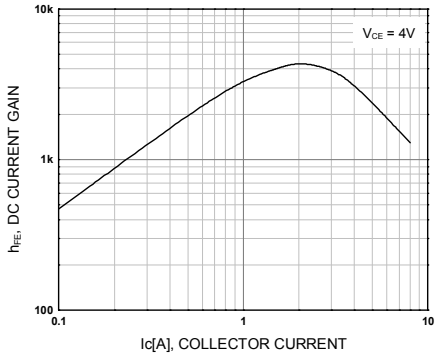


Figure 2. DC current Gain

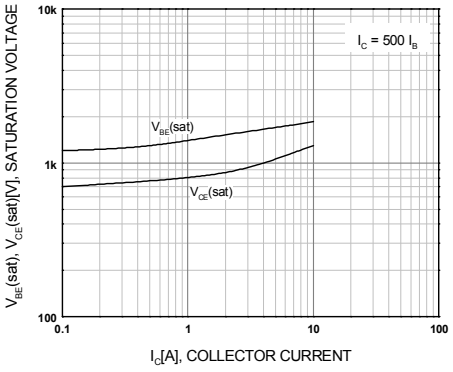


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

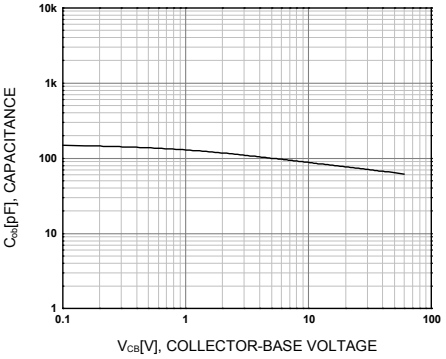


Figure 4. Collector Output Capacitance

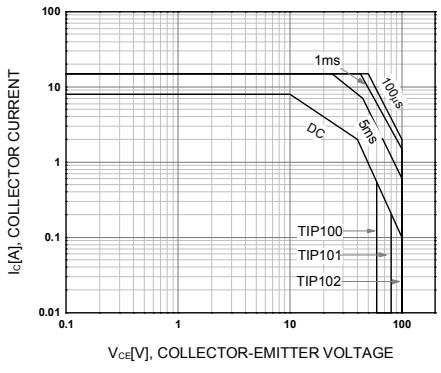


Figure 5. Safe Operating Area

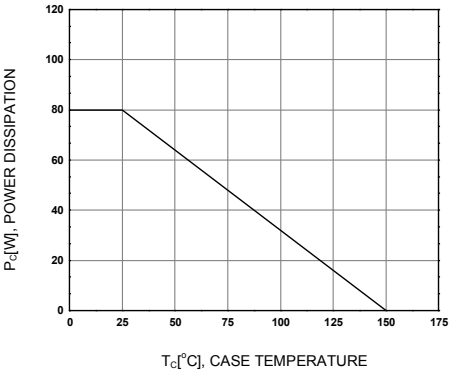
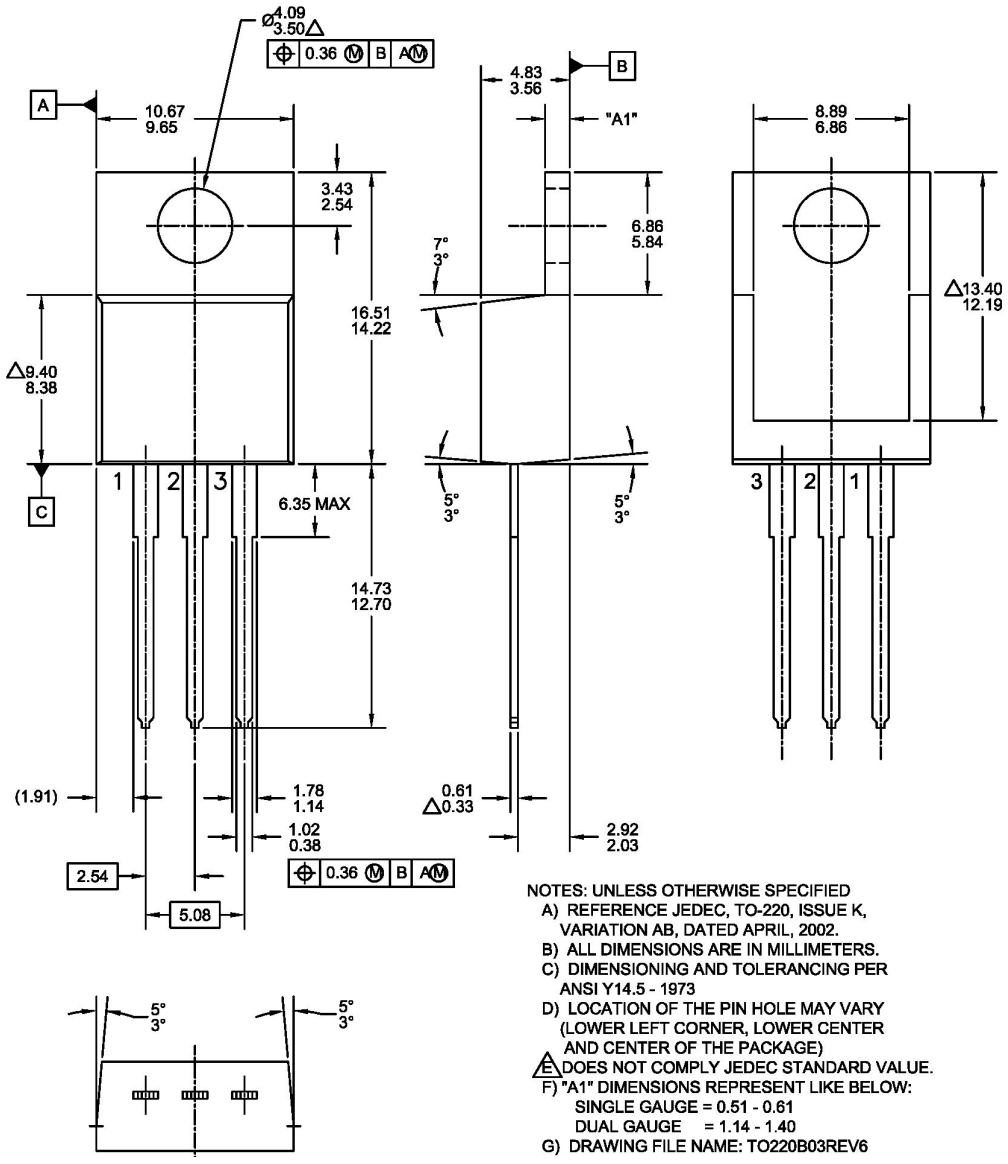


Figure 6. Power Derating

Mechanical Dimensions

TO220



NOTES: UNLESS OTHERWISE SPECIFIED

A) REFERENCE JEDEC, TO-220, ISSUE K, VARIATION AB, DATED APRIL, 2002.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5 - 1973
D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
E) DOES NOT COMPLY JEDEC STANDARD VALUE.
F) "A1" DIMENSIONS REPRESENT LIKE BELOW:
SINGLE GAUGE = 0.51 - 0.61
DUAL GAUGE = 1.14 - 1.40
G) DRAWING FILE NAME: TO220B03REV6

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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